THE DATASHEET OF

SK110B R5G

1A, 20V - 150V Surface Mount Schottky Barrier Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for over-voltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PARAMETERS		
PARAMETER	**VALUE**	**UNIT**
$I_{F(AV)}$	1	A
V_{RRM}	20 - 150	V
I_{FSM}	30	A
Package	DO-214AA (SMB)	
Configuration	Single Die	

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

Pb-Free RoHS COMPLIANT

MECHANICAL DATA

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Part no. with suffix “H” means AEC-Q101 qualified
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.093 g (approximately)

DO-214AA (SMB)

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

PARAMETER	SYMBOL	SK 12B	SK 13B	SK 14B	SK 15B	SK 16B	SK 19B	SK 110B	SK 115B	UNIT
Marking code on the device		SK 12B	SK 13B	SK 14B	SK 15B	SK 16B	SK 19B	SK 110B	SK 115B	
Repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	90	100	150	V
Reverse voltage, total rms value	$V_{R(RMS)}$	14	21	28	35	42	63	70	105	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	90	100	150	V
Forward current	$I_{F(AV)}$	1								A
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	30								A
Critical rate of rise of off-state voltage	dV/dt	10000								V/μs
Junction temperature	T_J	- 55 to +125			- 55 to +150					°C
Storage temperature	T_{STG}	- 55 to +150								°C

THERMAL PERFORMANCE			
PARAMETER	**SYMBOL**	**LIMIT**	**UNIT**
Junction-to-lead thermal resistance	$R_{\Theta JL}$	25	°C/W

ELECTRICAL SPECIFICATIONS (T_A = 25°C unless otherwise noted)						
PARAMETER		**CONDITIONS**	**SYMBOL**	**TYP**	**MAX**	**UNIT**
Forward voltage per diode (1)	SK12B	I_F = 1A,T_J = 25°C	V_F	-	0.50	V
	SK13B					V
	SK14B					V
	SK15B			-	0.75	V
	SK16B					V
	SK19B			-	0.85	V
	SK110B					V
	SK115B			-	0.95	V
Reverse current @ rated V_R per diode (2)	SK12B	T_J = 25°C	I_R	-	0.5	mA
	SK13B					mA
	SK14B					mA
	SK15B					mA
	SK16B					mA
	SK19B			-	0.1	mA
	SK110B					mA
	SK115B					mA
Reverse current @ rated V_R per diode (2)	SK12B	T_J = 100°C	I_R	-	10	mA
	SK13B					mA
	SK14B					mA
	SK15B			-	5	mA
	SK16B					mA
	SK19B			-	-	mA
	SK110B					mA
	SK115B					mA
Reverse current @ rated V_R per diode (2)	SK12B	T_J = 125°C	I_R	-	-	mA
	SK13B					mA
	SK14B					mA
	SK15B			-	-	mA
	SK16B					mA
	SK19B			-	2	mA
	SK110B					mA
	SK115B					mA

Notes:

1. Pulse test with PW=0.3 ms
2. Pulse test with PW=30 ms

ORDERING INFORMATION

PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING
SK1xxB (Note 1)	H	R5	G	SMB	850 / 7" Plastic reel
		R4		SMB	3,000 / 13" Paper reel
		M4		SMB	3,000 / 13" Plastic reel

Note:

1. "x" defines voltage from 20V (SK12B) to 150V (SK115B)

*: Optional available

EXAMPLE P/N

EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
SK16BHR5G	SK16B	H	R5	G	AEC-Q101 qualified Green compound

CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig1. Forward Current Derating Curve

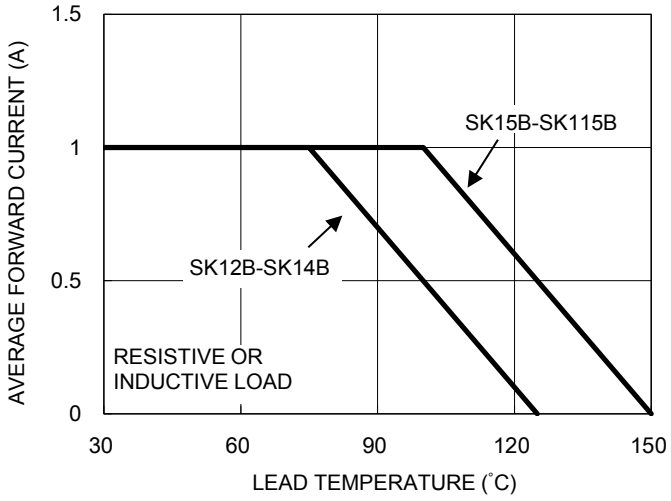


Fig2. Typical Junction Capacitance

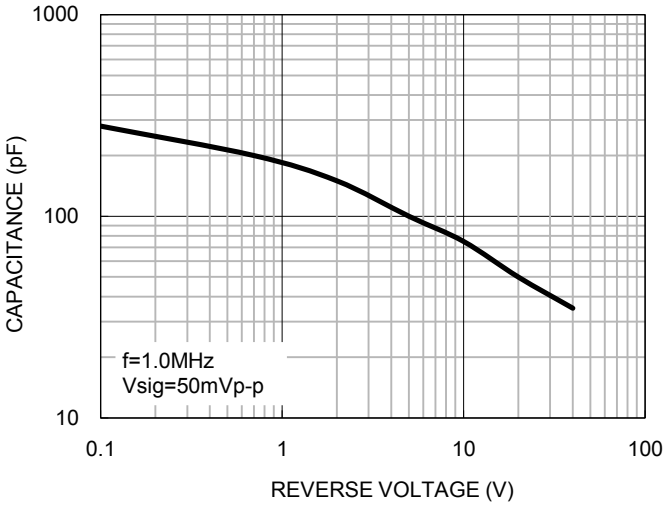


Fig3. Typical Reverse Characteristics

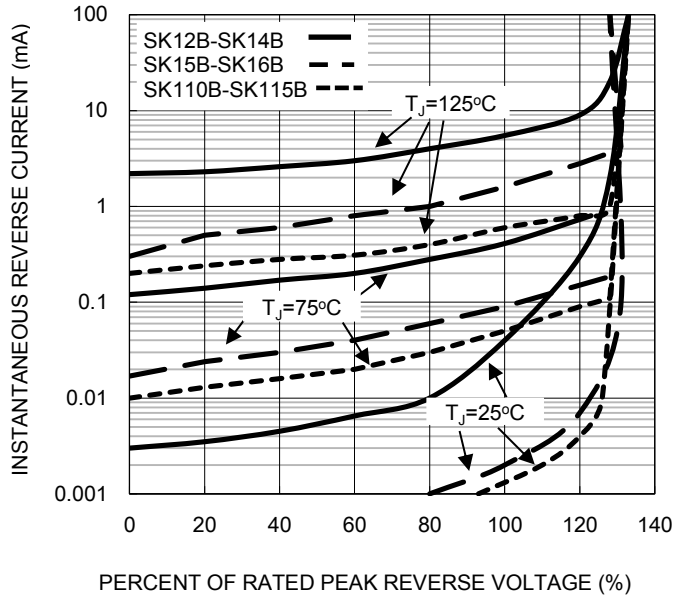
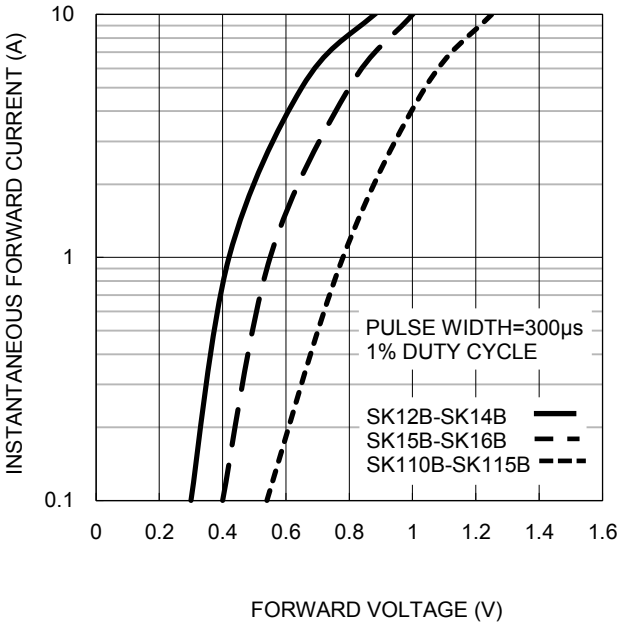


Fig4. Typical Forward Characteristics



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig5. Maximum Non-repetitive Forward Surge Current

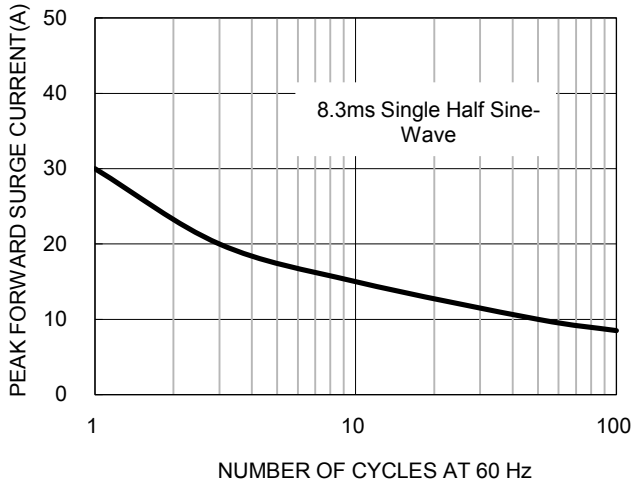
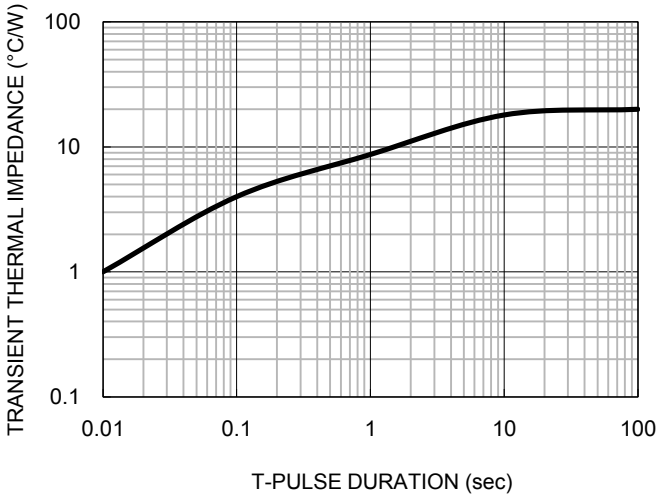
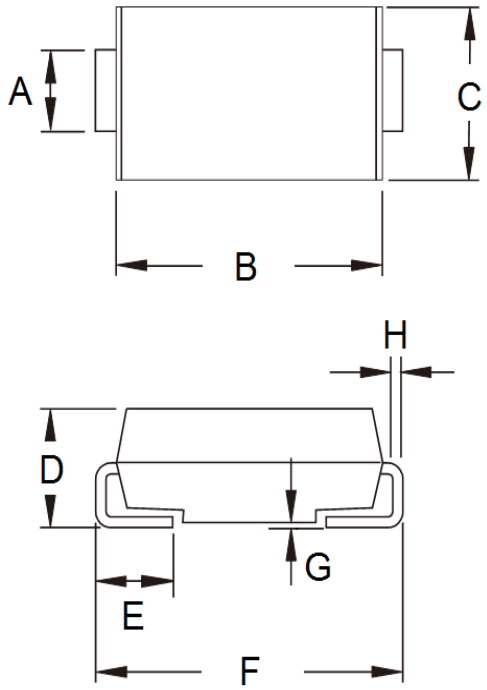


Fig6. Typical Transient Thermal Characteristics



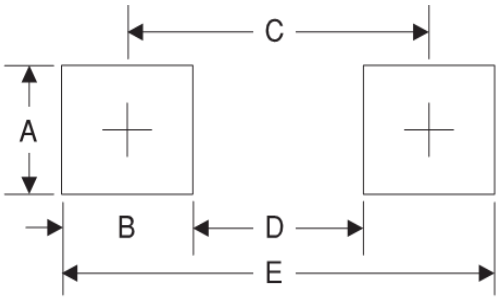
PACKAGE OUTLINE DIMENSIONS

DO-214AA (SMB)



DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.95	2.20	0.077	0.087
B	4.05	4.60	0.159	0.181
C	3.30	3.95	0.130	0.156
D	1.95	2.65	0.077	0.104
E	0.75	1.60	0.030	0.063
F	5.10	5.60	0.201	0.220
G	0.05	0.20	0.002	0.008
H	0.15	0.31	0.006	0.012

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	2.3	0.091
B	2.5	0.098
C	4.3	0.169
D	1.8	0.071
E	6.8	0.268

MARKING DIAGRAM

P/N = Marking Code
G = Green Compound
YW = Date Code
F = Factory Code

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